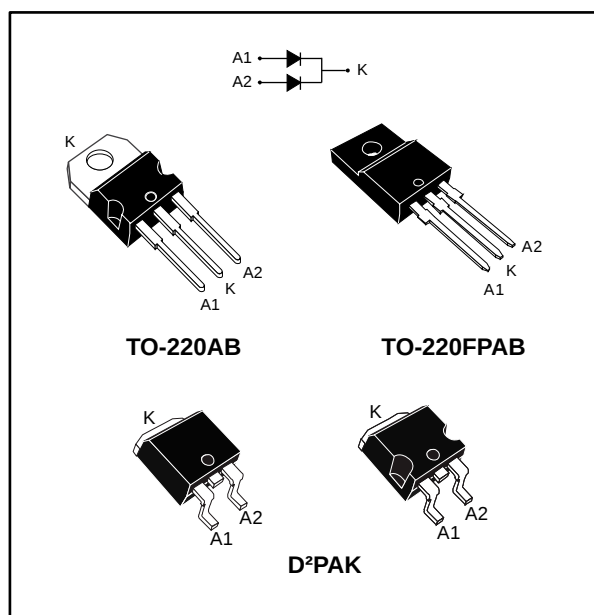


High efficiency ultrafast diode

Datasheet - production data



Description

Dual center tap rectifier suited for switch mode power supply and high frequency DC to DC converters.

Packaged either in TO-220AB, TO-220FPAB and D²PAK, this device is especially intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

Table 1: Device summary

Symbol	Value
$I_{F(AV)}$	Up to 2 x 10 A
V_{RRM}	200 V
T_j (max.)	175 °C
V_F (typ.)	0.78 V
t_{rr} (typ.)	21 ns

Features

- Suited for SMPS
- Low losses
- Low forward and reverse recovery time
- Low leakage current
- High junction temperature
- Insulated package: TO-220FPAB
 - insulating voltage: 2000 V_{RMS} sine
- ECOPACK®2 compliant component for D²PAK on demand

1 Characteristics

Table 2: Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified)

Symbol	Parameter				Value	Unit
V _{RRM}	Repetitive peak reverse voltage				200	V
I _{F(RMS)}	Forward rms current				30	A
I _{F(AV)}	Average forward current δ = 0.5, square wave	TO-220AB / D ² PAK	T _C = 150 °C	Per diode	8	A
			T _C = 140 °C	Per device	16	
			T _C = 140 °C	Per diode	10	
			T _C = 130 °C	Per device	20	
		TO-220FPAB	T _C = 130 °C	Per diode	8	
			T _C = 100 °C	Per device	16	
			T _C = 110 °C	Per diode	10	
			T _C = 75 °C	Per device	20	
I _{FSM}	Surge non repetitive forward current		t _p = 10 ms sinusoidal		80	A
T _{stg}	Storage temperature range				-65 to +175	°C
T _j	Maximum operating junction temperature				175	°C

Table 3: Thermal parameter

Symbol	Parameter			Value	Unit
R _{th(j-c)}	Junction to case	TO-220AB / D ² PAK	Per diode	3.0	°C/W
			Per device	1.9	
		TO-220FPAB	Per diode	5.5	
			Per device	4.5	
R _{th(c)}	Coupling	TO-220AB / D ² PAK		0.8	°C/W
		TO-220FPAB		3.5	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_{j(\text{diode1})} = P_{(\text{diode1})} \times R_{th(j-c)} (\text{per diode}) + P_{(\text{diode2})} \times R_{th(c)}$$

Table 4: Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25\text{ °C}$	$V_R = V_{RRM}$	-		6	μA
		$T_j = 125\text{ °C}$		-	4	60	
$V_F^{(2)}$	Forward voltage drop	$T_j = 25\text{ °C}$	$I_F = 8\text{ A}$	-		1.10	V
		$T_j = 150\text{ °C}$		-	0.78	0.89	
		$T_j = 25\text{ °C}$	$I_F = 16\text{ A}$	-		1.25	
		$T_j = 150\text{ °C}$		-		1.05	

Notes:(1)Pulse test: $t_p = 5\text{ ms}$, $\delta < 2\%$ (2)Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.73 \times I_{F(AV)} + 0.020 \times I_F^2(RMS)$$

Table 5: Dynamic electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
t_{rr}	Reverse recovery time	$T_j = 25\text{ °C}$	$I_F = 1\text{ A}$, $V_R = 30\text{ V}$, $di_F/dt = 100\text{ A}/\mu\text{s}$	-	21	26	ns
I_{RM}	Reverse recovery current	$T_j = 125\text{ °C}$	$I_F = 8\text{ A}$, $V_R = 160\text{ V}$, $di_F/dt = 200\text{ A}/\mu\text{s}$	-	6.8	8.8	A
t_{fr}	Forward recovery time	$T_j = 25\text{ °C}$	$I_F = 8\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$ $V_{FR} = 1.1 \times V_{Fmax}$	-		160	ns
V_{FP}	Forward recovery voltage		$I_F = 8\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$	-	2.4		V

1.1 Characteristics (curves)

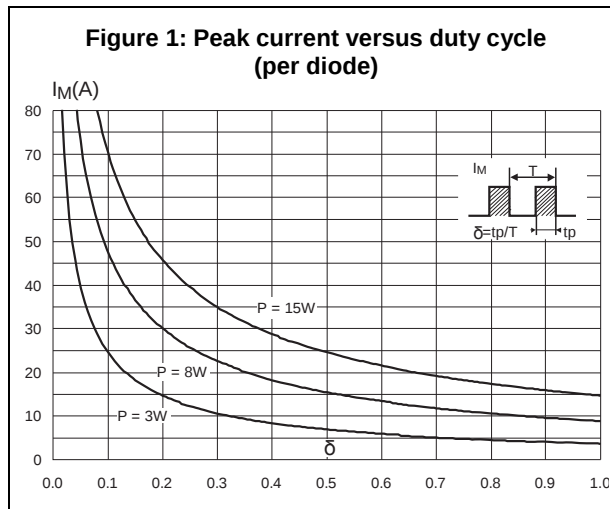


Figure 2: Forward voltage drop versus forward current (typical values, per diode)

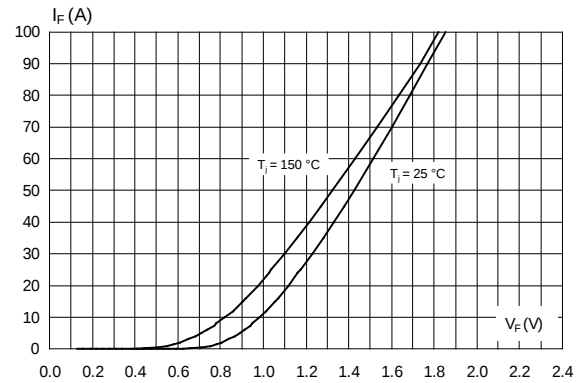


Figure 3: Forward voltage drop versus forward current (maximum values, per diode)

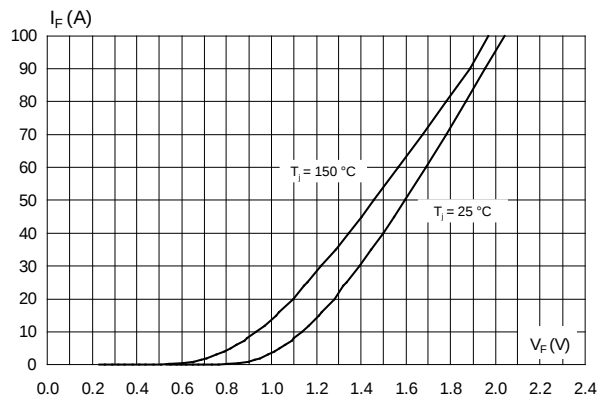


Figure 4: Relative variation of thermal impedance junction to case versus pulse duration (TO-220AB, D²PAK)

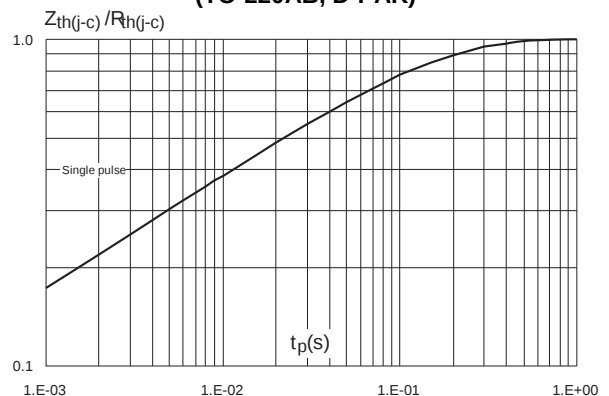


Figure 5: Relative variation of thermal impedance junction to case versus pulse duration (TO-220FPAB)

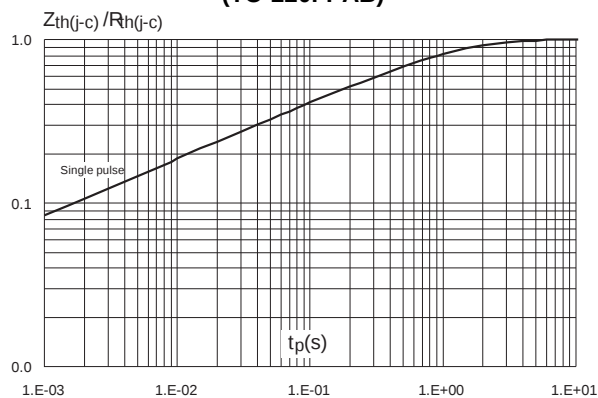


Figure 6: Junction capacitance versus reverse voltage applied (typical values, per diode)

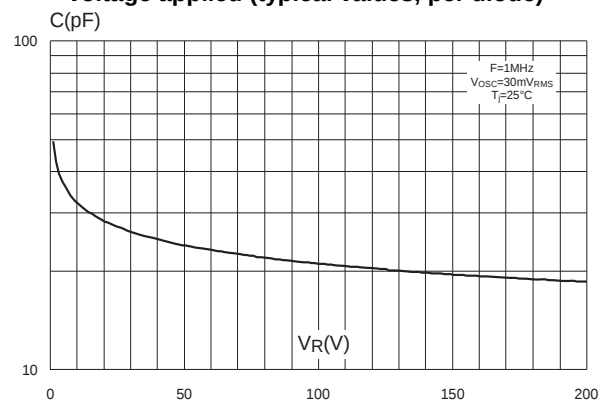
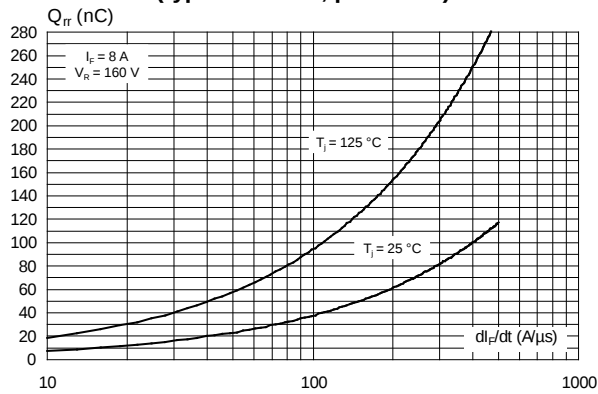
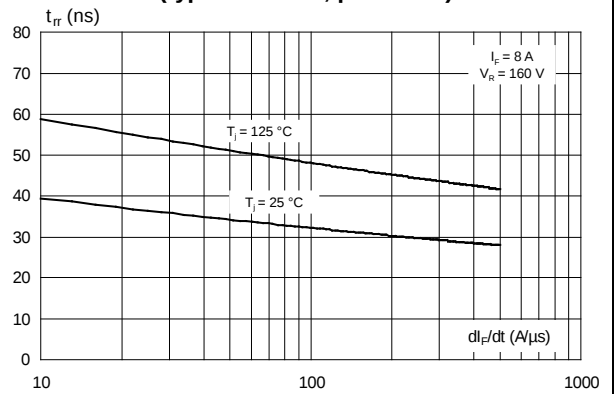
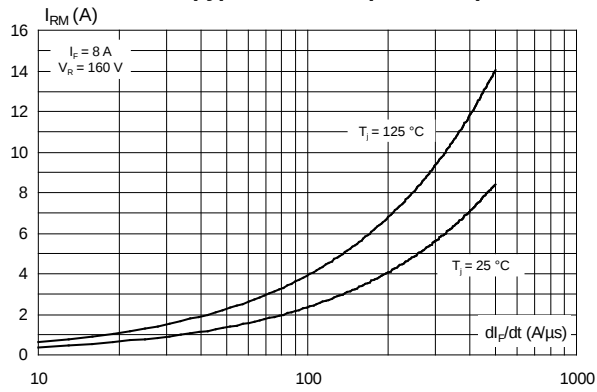
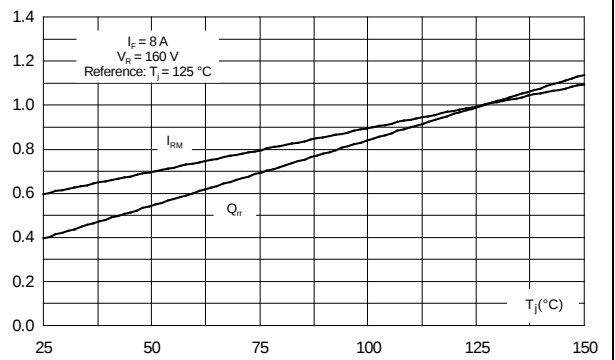
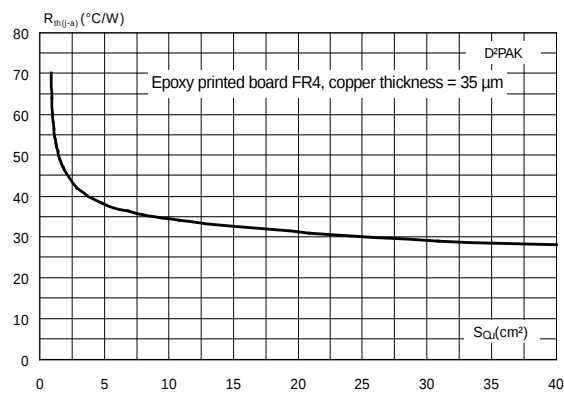


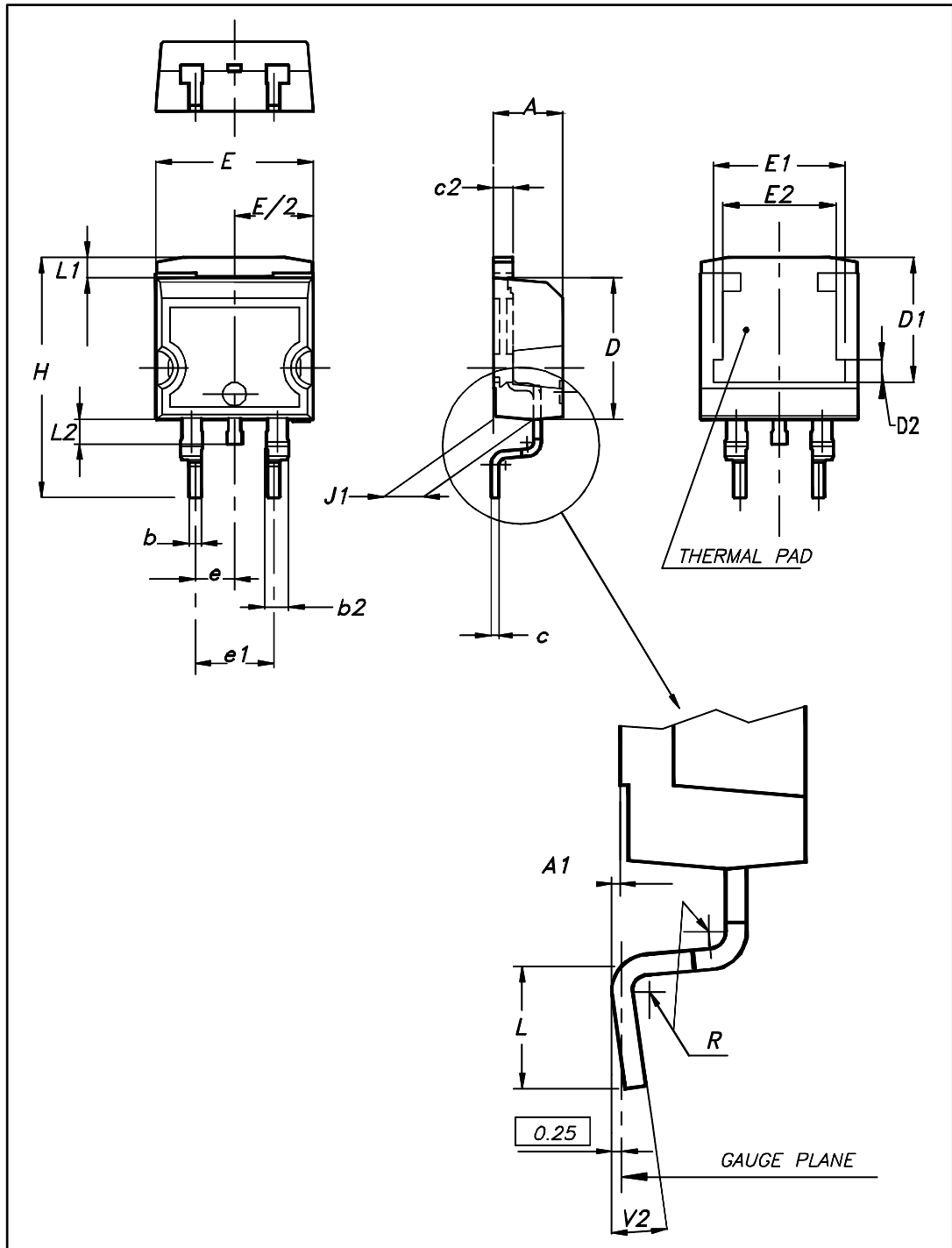
Figure 7: Reverse recovery charges versus di_F/dt (typical values, per diode)**Figure 8: Reverse recovery time versus di_F/dt (typical values, per diode)****Figure 9: Peak reverse recovery current versus di_F/dt (typical values, per diode)****Figure 10: Relative variation of dynamic parameters versus junction temperature****Figure 11: Thermal resistance junction to ambient versus copper surface under tab**

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

- Cooling method: by conduction (C)
- Epoxy meets UL94,V0
- Recommended torque value (TO-220AB and TO-220FPAB): 0.55 N.m
- Maximum torque value (TO-220AB and TO-220FPAB): 0.70 N.m

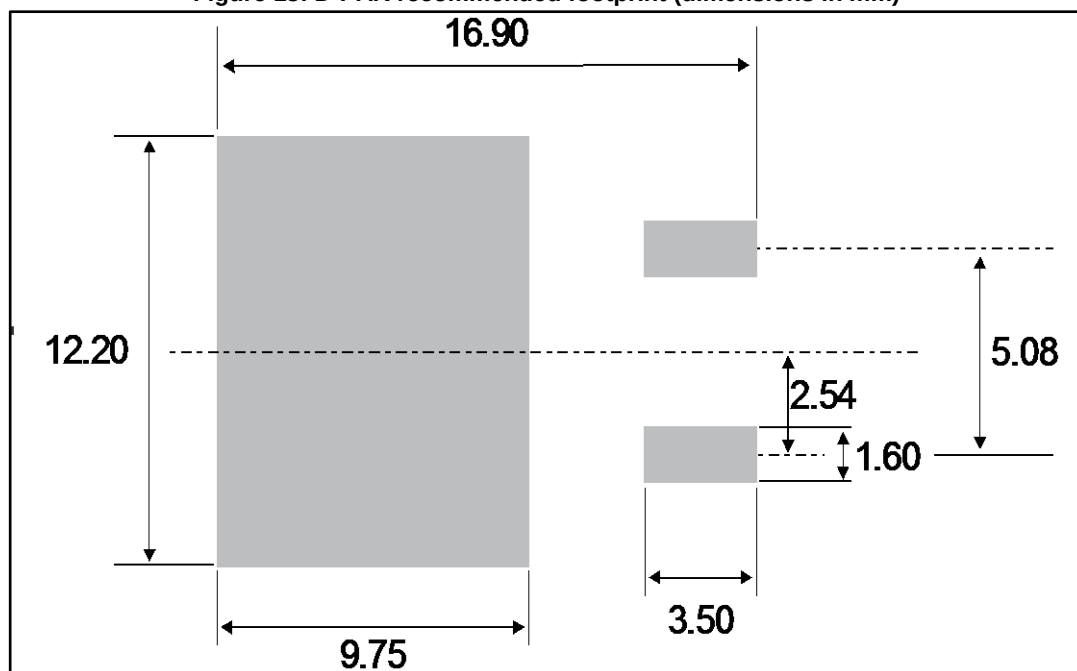
2.1 D²PAK package information

Figure 12: D²PAK package outline

This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Table 6: D²PAK package mechanical data

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.36	4.60	0.172	0.181
A1	0.00	0.25	0.000	0.010
b	0.70	0.93	0.028	0.037
b2	1.14	1.70	0.045	0.067
c	0.38	0.69	0.015	0.027
c2	1.19	1.36	0.047	0.053
D	8.60	9.35	0.339	0.368
D1	6.90	8.00	0.272	0.311
D2	1.10	1.50	0.043	0.060
E	10.00	10.55	0.394	0.415
E1	8.10	8.90	0.319	0.346
E2	6.85	7.25	0.266	0.282
e	2.54 typ.		0.100	
e1	4.88	5.28	0.190	0.205
H	15.00	15.85	0.591	0.624
J1	2.49	2.90	0.097	0.112
L	1.90	2.79	0.075	0.110
L1	1.27	1.65	0.049	0.065
L2	1.30	1.78	0.050	0.070
R	0.4 typ.		0.015	
V2	0°	8°	0°	8°

Figure 13: D²PAK recommended footprint (dimensions in mm)

2.2 TO-220AB package information

Figure 14: TO-220AB package outline

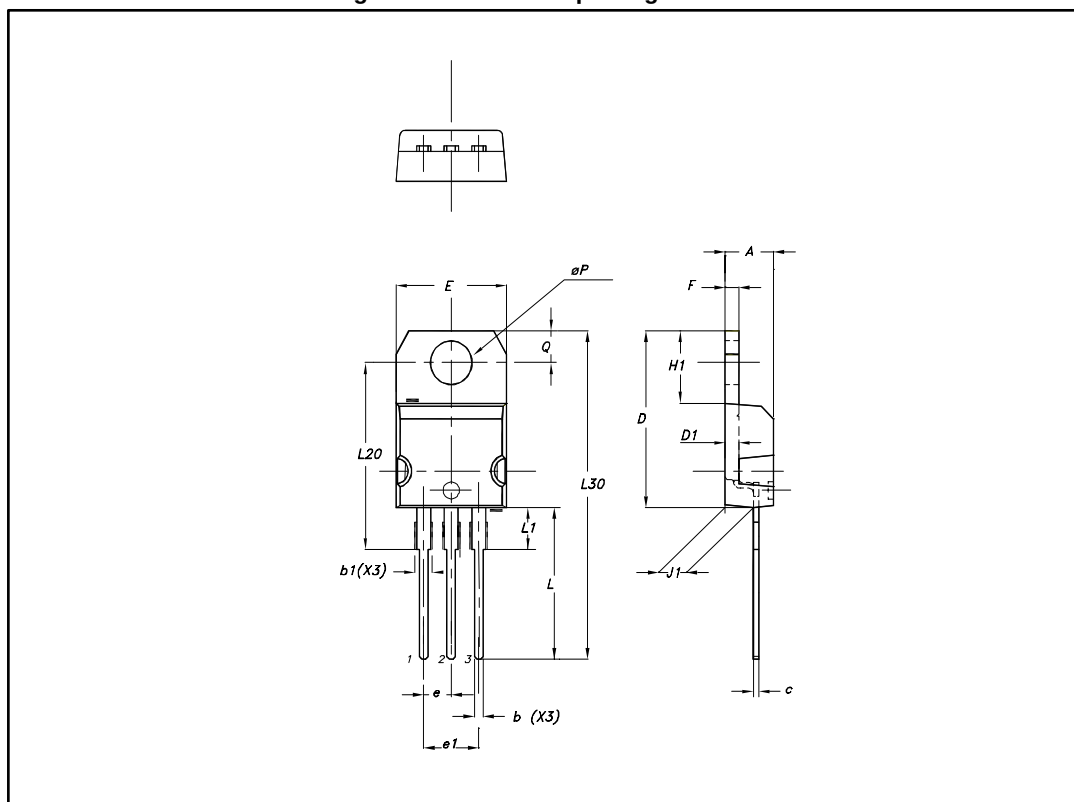


Table 7: TO-220AB package mechanical data

Ref.	Dimensions			
	Millimeters		Inches ⁽¹⁾	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.1732	0.1811
b	0.61	0.88	0.0240	0.0346
b1	1.14	1.70	0.0449	0.0669
c	0.48	0.70	0.0189	0.0276
D	15.25	15.75	0.6004	0.6201
D1	1.27 typ.		0.0500 typ.	
E	10.00	10.40	0.3937	0.4094
e	2.40	2.70	0.0945	0.1063
e1	4.95	5.15	0.1949	0.2028
F	1.23	1.32	0.0484	0.0520
H1	6.20	6.60	0.2441	0.2598
J1	2.40	2.72	0.0945	0.1071
L	13.00	14.00	0.5118	0.5512
L1	3.50	3.93	0.1378	0.1547
L20	16.40 typ.		0.6457 typ.	
L30	28.90 typ.		1.1378 typ.	
ØP	3.75	3.85	0.1476	0.1516
Q	2.65	2.95	0.1043	0.1161

Notes:⁽¹⁾Inch dimensions are for reference only.

2.3 TO-220FPAB package information

Figure 15: TO-220FPAB package outline

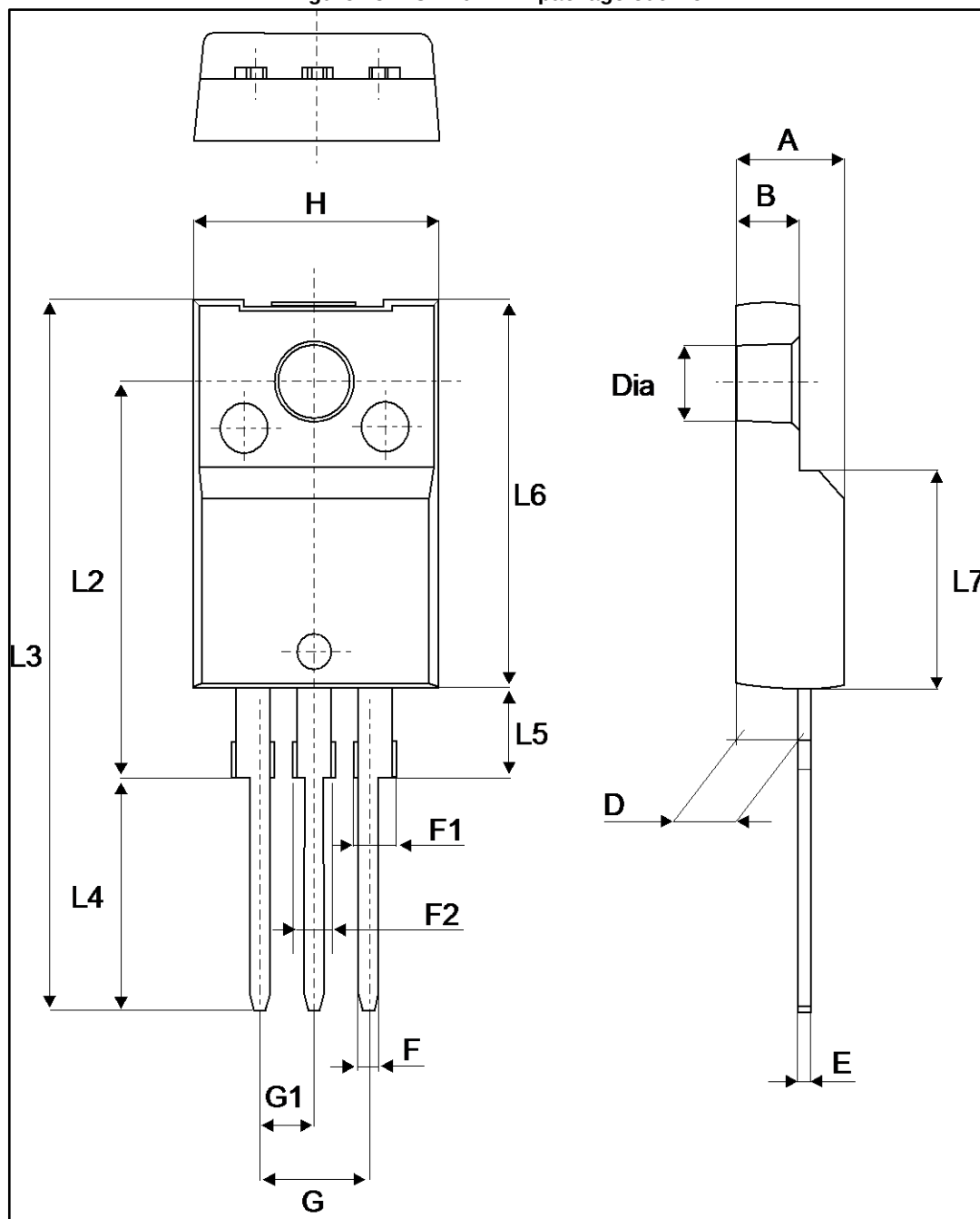


Table 8: TO-220FPAB package mechanical data

Ref.	Dimensions			
	Millimeters		Inches (for reference only)	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.1739	0.1818
B	2.5	2.7	0.0988	0.1067
D	2.50	2.75	0.0988	0.1087
E	0.45	0.70	0.0178	0.0277
F	0.75	1.0	0.0296	0.0395
F1	1.15	1.70	0.0455	0.0672
F2	1.15	1.70	0.0455	0.0672
G	4.95	5.20	0.1957	0.2055
G1	2.40	2.70	0.0949	0.1067
H	10.00	10.40	0.3953	0.4111
L2	16.00 typ.		0.6324 typ.	
L3	28.60	30.60	1.1304	1.2095
L4	9.80	10.6	0.3874	0.4190
L5	2.90	3.60	0.1146	0.1423
L6	15.90	16.40	0.6285	0.6482
L7	9.00	9.30	0.3557	0.3676
Dia	3.0	3.20	0.1186	0.1265

3 Ordering information

Table 9: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STTH1602CG-TR	STTH1602CG	D ² PAK	1.38 g	1000	Tape and reel
STTH1602CT	STTH1602CT	TO-220AB	1.90 g	50	Tube
STTH1602CFP	STTH1602CFP	TO-220FPAB	1.70 g	50	Tube

4 Revision history

Table 10: Document revision history

Date	Revision	Changes
Feb-2004	1	First release
23-Apr-2014	2	Updated ECOPACK statement. Reformatted to current standards. Updated <i>Section 2: Package mechanical data</i>
11-Aug-2017	3	Updated features, package silhouette and Table 1: "Device summary" . Updated Section 1: "Characteristics" , Section 2: "Package information" and Section 3: "Ordering information" .

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